

Vishay General Semiconductor

Surface Mount PAR[®] Transient Voltage Suppressors

High Temperature Stability and High Reliability Conditions



SMC (DO-214AB)

LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
V _{WM}	10 V to 43 V				
V _{BR}	11.1 V to 52.8 V				
P _{PPM}	3000 W				
PD	6.0 W				
I _{FSM}	200 A				
T _J max.	185 °C				
Polarity	Uni-directional				
Package	SMC (DO-214AB)				

FEATURES

 Junction passivation optimized design passivated anisotropic rectifier technology



COMPLIANT

HALOGEN

- T_J = 185 °C capability suitable for high reliability and automotive requirement
- Available in uni-directional polarity only
- 3000 W peak pulse power capability with a 10/1000 μs waveform
- Excellent clamping capability
- Very fast response time
- · Low incremental surge resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available
 Automotive ordering code: base P/NHE3 or P/NHM3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting on ICs, MOSFET, signal lines of sensor units for consumer, computer, industrial, automotive, and telecommunication.

MECHANICAL DATA

Case: SMC (DO-214AB)

Molding compound meets UL 94 V-0 flammability rating Base P/NHE3_X - RoHS-compliant and AEC-Q101 qualified Base P/NHM3_X - halogen-free, RoHS-compliant and AEC-Q101 qualified

("X" denotes revision code e.g. A, B, ...)

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

HE3 and HM3 suffix meet JESD 201 class 2 whisker test

Polarity: color band denotes cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	VALUE	UNIT			
Peak pulse power dissipation with a 10/1000 μs waveform $^{(1)}$ (fig. 3)	P _{PPM}	3000	W			
Peak power pulse current with a 10/1000 μs waveform $^{(1)}$ (fig. 1)	I _{PPM}	See next table	А			
Peak forward surge current 8.3 ms single half sine-wave (2)	I _{FSM}	200	А			
Power dissipation on infinite heatsink, T_L = 75 °C (fig. 6)	PD	6.0	W			
Maximum instantaneous forward voltage at 100 A (2)	V _F	3.5	V			
Operating junction and storage temperature range	T _J , T _{STG}	-65 to +185	°C			

Notes

 $^{(1)}$ Non-repetitive current pulse, per fig. 3 and derated above T_A = 25 °C per fig. 2.

(2) Measured on 8.3 ms single half sine-wave, or equivalent square wave, duty cycle = 4 pulses per minute maximum

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DEVICE TYPE	DEVICE MARKING CODE	BREAKDOWN VOLTAGE V _{BR} AT I _T ⁽¹⁾ (V)			STAND-OFF VOLTAGE V _{WM}	MAXIMUM REVERSE LEAKAGE AT V _{WM}	MAXIMUM REVERSE LEAKAGE AT V _{WM}	MAXIMUM PEAK PULSE SURGE	MAXIMUM CLAMPING VOLTAGE AT I _{PPM}	TYPICAL TEMP. COEFFICIENT OF V _{BR} ⁽³⁾	
		MIN.	NOM.	MAX.	(mA)	M	I _R (μΑ)	I _D (μΑ) T _J = 150 °C	CURRENT I _{PPM} (A) ⁽²⁾	V _c (V)	αT (%/°C)
3KASMC10A	3AX	11.1	11.7	12.3	1.0	10	5.0	50	177	17.0	0.069
3KASMC11A	3AZ	12.2	12.9	13.5	1.0	11	5.0	50	165	18.2	0.072
3KASMC12A	3BE	13.3	14.0	14.7	1.0	12	2.0	20	151	19.9	0.074
3KASMC13A	3BG	14.4	15.2	15.9	1.0	13	2.0	20	140	21.5	0.076
3KASMC14A	3BK	15.6	16.4	17.2	1.0	14	1.0	10	129	23.2	0.078
3KASMC15A	3BM	16.7	17.6	18.5	1.0	15	1.0	10	123	24.4	0.080
3KASMC16A	3BP	17.8	18.8	19.7	1.0	16	1.0	10	115	26.0	0.081
3KASMC17A	3BR	18.9	19.9	20.9	1.0	17	1.0	10	109	27.6	0.082
3KASMC18A	3BT	20.0	21.1	22.1	1.0	18	1.0	10	103	29.2	0.083
3KASMC20A	3BV	22.2	23.4	24.5	1.0	20	1.0	10	92.6	32.4	0.085
3KASMC22A	3BX	24.4	25.7	26.9	1.0	22	1.0	10	84.5	35.5	0.086
3KASMC24A	3BZ	26.7	28.1	29.5	1.0	24	1.0	10	77.1	38.9	0.087
3KASMC26A	3CE	28.9	30.4	31.9	1.0	26	1.0	10	71.3	42.1	0.088
3KASMC28A	3CG	31.1	32.8	34.4	1.0	28	1.0	10	66.1	45.4	0.089
3KASMC30A	3CK	33.3	35.1	36.8	1.0	30	1.0	15	62.0	48.4	0.090
3KASMC33A	3CM	36.7	38.7	40.6	1.0	33	1.0	15	56.3	53.3	0.091
3KASMC36A	3CP	40.0	42.1	44.2	1.0	36	1.0	20	51.6	58.1	0.091
3KASMC40A	3CR	44.4	46.8	49.1	1.0	40	1.0	20	46.5	64.5	0.092
3KASMC43A	3CT	47.8	50.3	52.8	1.0	43	1.0	20	43.2	69.4	0.093

Notes

⁽¹⁾ Pulse test: $t_p \le 50 \text{ ms}$

⁽²⁾ Surge current waveform per fig. 3 and derate per fig. 2

⁽³⁾ To calculate V_{BR} vs. junction temperature, use the following formula: V_{BR} at T_J = V_{BR} at 25 °C x (1 + α T x (T_J - 25))

⁽⁴⁾ All terms and symbols are consistent with ANSI/IEEE C62.35

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL	VALUE	UNIT			
Typical thermal resistance, junction to ambient air ⁽¹⁾ $R_{\theta JA}$ 7			°C/W			
Typical thermal resistance, junction to leads	$R_{ extsf{ heta}JL}$	18.3	C/ W			

Note

⁽¹⁾ Mounted on minimum recommended pad layout

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
3KASMC10AHE3_B/H ⁽¹⁾	0.211	Н	850	7" diameter plastic tape and reel		
3KASMC10AHE3_B/I (1)	0.211	l	3500	13" diameter plastic tape and reel		
3KASMC10AHM3_B/H ⁽¹⁾	0.211	Н	850	7" diameter plastic tape and reel		
3KASMC10AHM3_B/I (1)	0.211	l	3500	13" diameter plastic tape and reel		

Note

(1) AEC-Q101 qualified

Revision: 20-Jul-2020

2



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RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

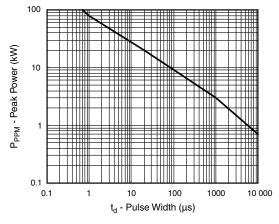


Fig. 1 - Peak Pulse Power Rating Curve

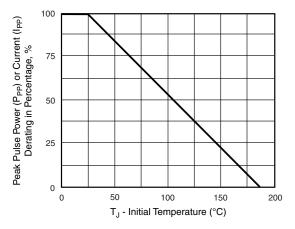


Fig. 2 - Pulse Power or Current vs. Initial Junction Temperature

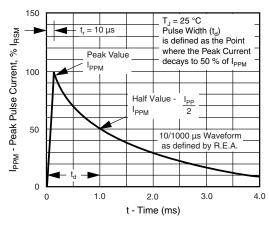


Fig. 3 - Pulse Waveform

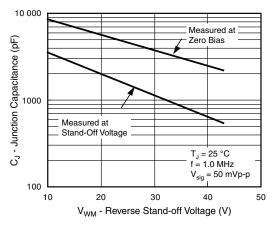


Fig. 4 - Typical Junction Capacitance

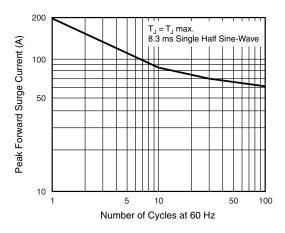


Fig. 5 - Maximum Non-Repetitive/Peak Forward Surge Current

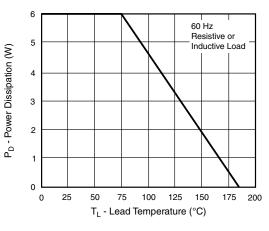


Fig. 6 - Power Derating Curve

Revision: 20-Jul-2020

3

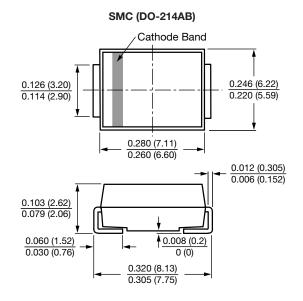
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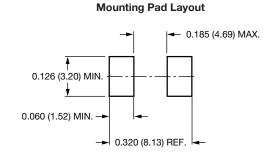
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)







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